

General Description

SN74LVC1G08 is a 2-input and gate integrated circuit, which can realize the mathematical logic operation of 74LV. Advanced CMOS process design, with low power consumption and high output driving capability, the power supply voltage VCC between 1.65V and 5.5V chip can work normally.SN74LVC1G08 has a variety of small encapsulation shapes, which can be widely used in high-end precision instruments, miniaturized and low-power handheld devices and artificial intelligence.

Features

- Low input current.
- Low static power consumption.lcc=0.1uA.
- High output drive.VCC=4.5V.
- Wide operating voltage range.1.65V-5.5V
- Packaging form:DBV/DRL/YZP/DCK DRP/DSF/DPW

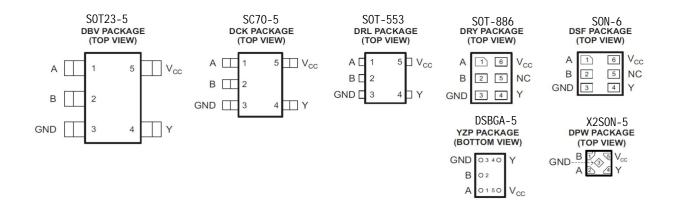
Applications

- Portable audio interface
- Blu-ray players and home theaters
- Solid state drives

- Digital TV
- Wireless headphones, smart watches, etc
- Smart wearable Devices

Pinning and Package

www.tw-gmc.com



Pin Functions

PIN								
NAME	DBV, DCK, DRL, YZP	DRY, DSF	DPW	DESCRIPTION				
Α	1	1	2	Input				
В	2	2	1	Input				
GND	3	3	3	Ground				
Υ	4	4	4	Output				
V_{CC}	5	6	5	Power pin				
NC		5		Not connected				

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Absolute Maximum Ratings

			MIN	MAX	UNIT
V_{CC}	Supply voltage range	-0.5	6.5	V	
V_{I}	Input voltage range (2)			6.5	V
Vo	Voltage range applied to any output in the high-i	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high of	-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
T _J (max)	Junction temperature			150	°C
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Functional Block Diagram



Device Functional Modes

Inp	uts	Output				
A	В	Y				
L	L	L				
L	Н	L				
Н	L	L				
Н	Н	Н				

Recommended Operating Conditions

			MIN	MAX	UNIT				
\/	Cupply voltogo	Operating	1.65	5.5	V				
V _{CC}	Supply voltage	Data retention only	1.5		V				
V _{IH}		V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}						
	High level input values	V_{CC} = 2.3 V to 2.7 V	1.7		V				
	High-level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2		V				
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0.7 × V _{CC}						
		V _{CC} = 1.65 V to 1.95 V		0.35 × V _{CC}).35 × V _{CC}				
.,	Lave lavel innert valtage	V _{CC} = 2.3 V to 2.7 V		0.7	V				
V _{IL}	Low-level input voltage	V _{CC} = 3 V to 3.6 V		0.8					
		V _{CC} = 4.5 V to 5.5 V		0.3 × V _{CC}					
VI	Input voltage	•	0	5.5	V				
Vo	Output voltage		0	V _{CC}	V				
		V _{CC} = 1.65 V		-4					
		V _{CC} = 2.3 V		-8					
I _{OH}	High-level output current	V 2.V		-16	mA				
		$V_{CC} = 3 V$		-24					
		V _{CC} = 4.5 V		-32					
		V _{CC} = 1.65 V		4					
		V _{CC} = 2.3 V		8					
I _{OL}	Low-level output current			16	mA				
		$V_{CC} = 3 V$		24					
		V _{CC} = 4.5 V	32	ļ					

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The value of V_{CC} is provided in the *Recommended Operating Conditions* table.



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	Vcc	TYP	MAX	UNIT	
		I _{OH} =-100uA	1.65V~5.5V	1.64	-	V	
		I_{OH} =-4 mA	1.65V	1.47	-		
V_{OH}		$I_{OH} = -8 \text{ mA}$	2. 3V	2.15	_		
		I _{OH} =-16 mA	3V	2.73	_		
		I_{OH} =-32 mA	4. 5V	4.0			
		$I_{OH} = 100uA$	1.65V~5.5V	0.01	_		
		I_{OH} =4 mA	1.65V	0.11	_		
V_{OL}		I _{OH} =8 mA	2. 3V	0.11	_	V	
		I_{OH} =16 mA	3V	0.2	-		
		I_{OH} =32 mA	4. 5V	0.35	_		
$I_{\mathbf{I}}$	A	$V_{\rm I}$ =5.5V or GND	0~5.5V	0.01	±5	uA	
11	В	VI -0. 5V OI GND	0 5.50	0.01	±5		
${ m I}_{\sf OFF}$	$V_{\mathbf{I}}$	$V_{I} = 5.5V$	0	0.01	±10	uA	
10FF	Vo	$V_0 = 5.5V$	0	0.01	±10	uA	
т.		$V_{I} = 5.5V$, $I_{O} = 0$	1. 65V~5. 5V	0.01	0.01 10		
I_{CC}		$V_I = GND$, $I_O = 0$	1.007 5.57	0.01	10	u A	
		$A=V_{CC}-0.6V$		25	_	11.Λ	
A T		B=V _{CC} or GND	3V~5.5V			uA	
ΔI_{CC}		B=V _{CC} -0.6V		25	_	11Λ	
		$A=V_{CC} ext{ or GND}$				uA	

⁽¹⁾ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

Switching Characteristics, $C_L = 15 pF$

over recommended operating free-air temperature range (unless otherwise noted) (see

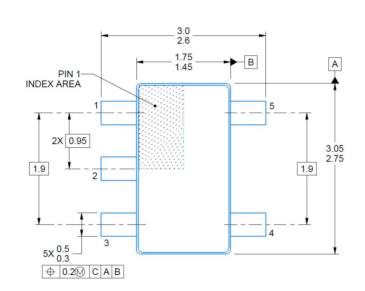
		TO (OUTPUT)	−40°C to 85°C								
PARAMETER	FROM (INPUT)		V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y	1.5	7.2	0.7	4.4	0.8	3.6	0.8	3.4	ns

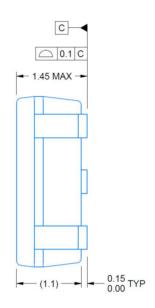
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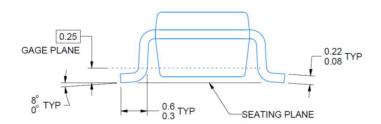


Package Outline

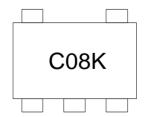
DBV (SOT23-5)





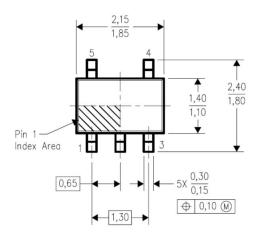


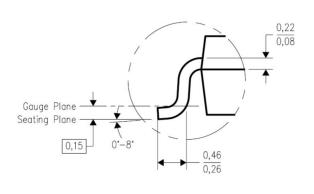
Marking

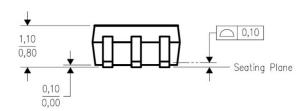


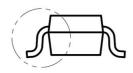


DCK (SC70-5)

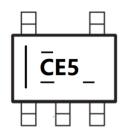






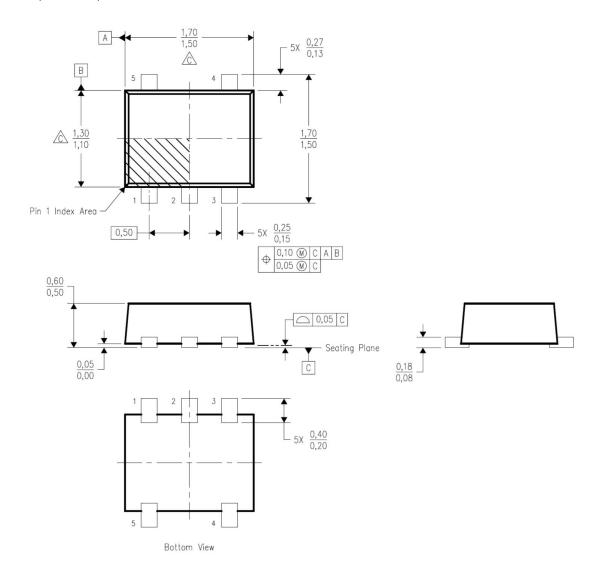


Marking



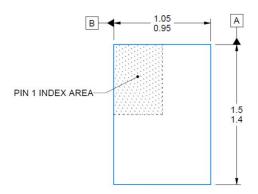


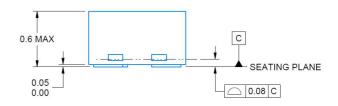
DRL (SOT-553)

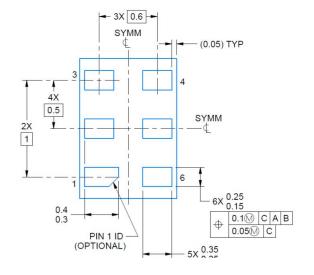


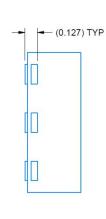


DRY (SOT-886)



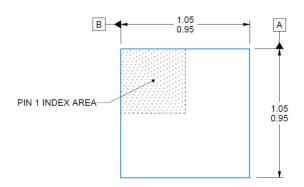


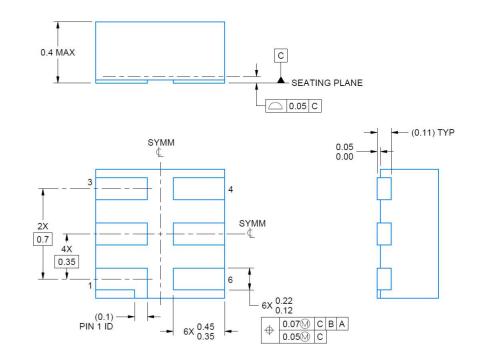






DSF (SON-6)

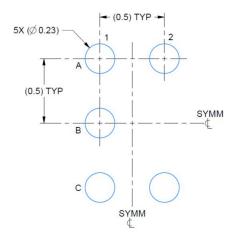




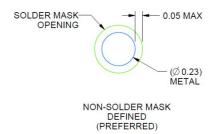
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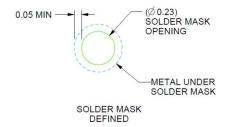


YZP (DSBGA-5)



LAND PATTERN EXAMPLE SCALE:40X







DPW (X 2SON-5)

